



N-CHANNEL ENHANCEMENT MODE MOSFET

#### Features

- Low On-Resistance: R<sub>DS(ON)</sub>
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

#### **Mechanical Data**

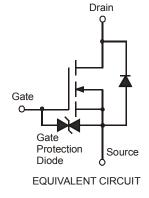
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Alloy 42
  leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

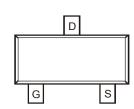




SOT23

Top View





Top View Pin Out Configuration

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN601K-7	SOT23	3000/Tape & Reel

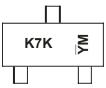
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

# **Marking Information**



Chengdu A/T Site

<b>К7К</b>	ΜY

Shanghai A/T Site

K7K = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)  $\overline{YM}$  = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or  $\overline{Y}$  = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key
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Year	2005	2006	2007	2008	2009	2010	2011	2011	2012	2013	2014	2015	2016	2017
Code	S	Т	U	V	W	Х	Y	Y	Z	А	В	С	D	E
Month	Jan	Feb	M	ar	Apr	Мау	Jun	Jul	Aug	Se	p	Oct	Nov	Dec
Code	1	2	3	5	4	5	6	7	8	9		0	Ν	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		V <sub>DSS</sub>	60	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Drain Current (Note 5)	Continuous Pulsed (Note 6)	ID	300 800	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient	$R_{ extsf{ heta}JA}$	357	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C

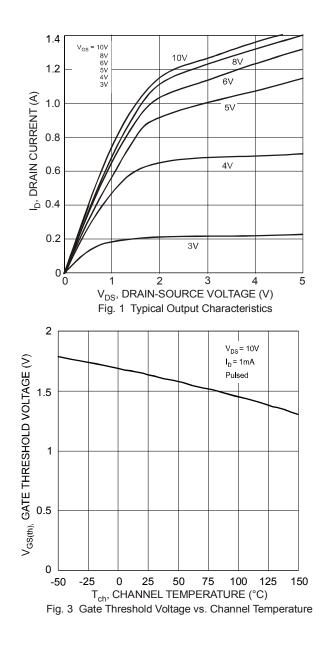
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						l
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60			V	$V_{GS} = 0V, I_{D} = 10\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_		1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.0	1.6	2.5	V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA
Static Drain-Source On-Resistance		_	_	2.0	Ω	V <sub>GS =</sub> 10V, I <sub>D</sub> = 0.5A
	R <sub>DS(ON)</sub>	)	—	3.0		V <sub>GS</sub> = 5V, I <sub>D</sub> = 0.05A
Forward Transfer Admittance	Y <sub>fs</sub>	80	_		ms	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.2A
DYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss	_	_	50	pF	
Output Capacitance	Coss	_		25	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>			5.0	pF	1

Notes:

Device mounted on FR-4 PCB.
 Pulse width ≤10µS, Duty Cycle ≤1%.
 Short duration pulse test used to minimize self-heating effect.





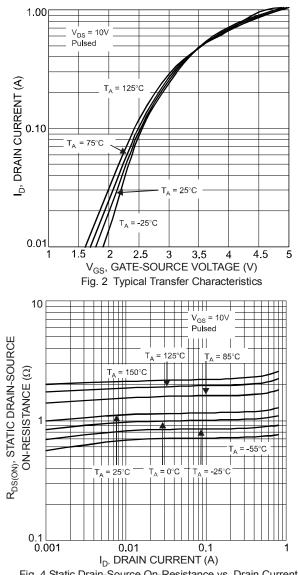
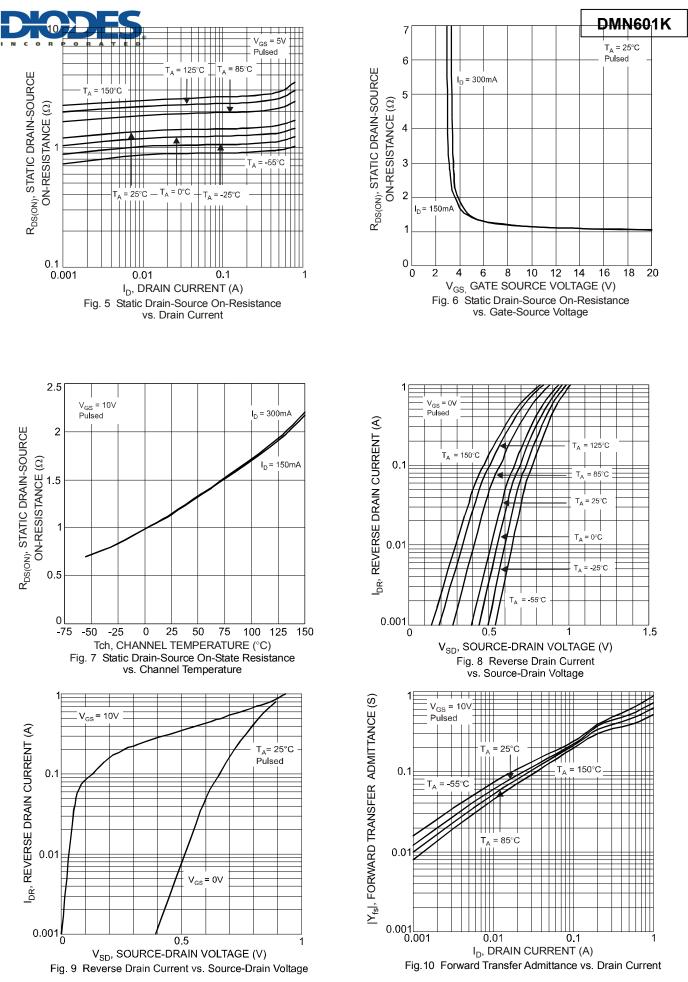


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current

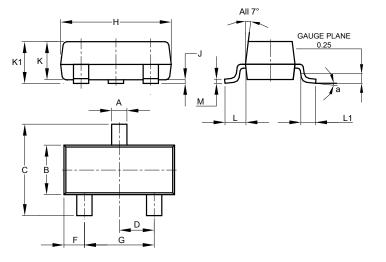


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## Package Outline Dimensions

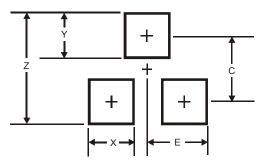
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
α	8°							
All	Dimens	ions in	mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
ш	1.35

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#### DMN601K

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